NSN 5962-01-610-2025

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-610-2025 **Body Length:** Between 1.4 millimeters and 1.7 millimeters **Body Width:** Between 1.4 millimeters and 1.7 millimeters **Body Height:** Between 0.6 millimeters and 1.1 millimeters **Operating Tempurature Range:** -40.0 to 85.0 degrees celsius **Storage Tempurature Range:** -65.0 to 150.0 degrees celsius **End Application:** Ghawk asip **Features Provided:** Asynchronous and synchronous and programmable and high performance and low voltage and w/reset **Inclosure Material:** Metal **Inclosure Configuration:** Pin grid array **Case Outline Source And Designator:** Mo-192-bau-1 joint electron device engineering council **Product Name:** Virtex 2.5v field programmable gate arrays **Voltage Rating And Type Per Characteristic:** 2.5 volts input **Memory Device Type:** Programmable **Special Features:** Cavity down pk; system grates 322, 970; clb arrary-32x48; logic cells-6, 912; maximum avail i/o-316; block ram bits-65, 536; max selectram+ bits 98, 304 **Terminal Type And Quantity:** 432 bonding pad **Specification Or Standard:** 5 speed Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Yes - demil/mli

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